



Notice

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Agilent Technologies

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Introduction

Agilent Technologies E4438C ESG vector signal generator incorporates a broad array of capabilities for testing both analog and digital communications systems. Flexible options provide test solutions that will evaluate the performance of nearly all current and proposed air interface standards. Many test functions can be customized to meet the needs of proprietary and other nonstandard wireless protocols as well. You can configure your instrument to address a wide variety of tests—from altering nearly every aspect of a digital signal or signal operating environment, to creating experimental signals. This flexibility, along with an architecture that accepts future enhancements makes the E4438C ESG vector signal generator an excellent choice for wireless communications system testing now and in the future.

E4438C ESG vector signal generator

Choose your required frequency range as an *Option* when configuring your E4438C ESG vector signal generator. Please refer to the *E4438C Configuration Guide* for complete ordering information. Literature number 5988-4085EN.

Definitions

Specifications (spec): Specifications describe the instrument's warranted performance and apply after a 45 minute warm-up. All specifications are valid over the signal generators entire operating/environmental range unless otherwise noted. Supplemental characteristics, denoted typical or nominal, provide additional [nonwarranted] information useful in applying the instrument. Column headings labeled "standard" imply that this level of performance is standard, without regard for option configuration. If a particular option configuration modifies the standard performance, that performance is given in a separate column.

Typical (typ): performance is not warranted. It applies at 25°C. 80% of all products meet typical performance.

Nominal (nom): values are not warranted. They represent the value of a parameter that is most likely to occur; the expected or mean value. They are included to facilitate the application of the product.

Standard (std): No options are included when referring to the signal generator unless noted otherwise.

Key standard features

- Expandable architecture
- Broad frequency coverage
- Choice of electronic or mechanical attenuator
- Superior level accuracy
- Wideband FM and ΦM
- · Step and list sweep, both frequency and power
- Built-in function generator
- · Lightweight, rack-mountable
- 1-year standard warranty
- 2-year calibration cycle
- Broadband analog I/Q inputs
- I/Q adjustment capabilities and internal calibration routine
- · Excellent modulation accuracy and stability
- · Coherent carrier output up to 4 GHz

Optional features

- Internal baseband generator, 8 or 64 MSa (40 or 320 MB) memory with digital bus capability
- ESG digital input or output connectivity with N5102A Baseband Studio digital signal interface module
- 6 GB internal hard drive
- Internal bit error rate (BER) analyzer
- · High-stability time-base
- Enhanced phase noise performance
- · High output power with mechanical attenuator
- Move all front panel connectors to the rear panel
- 3GPP W-CDMA FDD personality
- cdma2000 and IS-95-A personality
- TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA)
- · Calibrated noise (AWGN) personality
- GPS personality
- Signal Studio for 1xEV-DO
- Signal Studio for 1xEV-DV and cdma2000
- Signal Studio for 802.11 WLAN
- Signal Studio for *Bluetooth*™
- Signal Studio for enhanced multitone
- Signal Studio for HSDPA over W-CDMA
- Signal Studio for TD-SCDMA (TSM)
- Signal Studio for noise power ratio (NPR)
- Signal Studio for S-DMB
- Signal Studio for pulse building
- · Signal Studio for jitter injection
- Signal Studio toolkit
- Signal Studio for 802.16-2004 (WiMAX)

This document contains the measured specifications for the instrument platform and personalities. It does not contain a full list of features for all optional personalities. Please consult the individual product overviews for each personality for a full listing of all features and capabilities. These are listed at the end of this document.

⁴ www.valuetronics.com

Frequency

Frequency range

	.90		
Option ¹			
501	250 kHz to 1 GHz		
502	250 kHz to 2 GHz		
503	250 kHz to 3 GHz		
504	250 kHz to 4 GHz		
506	250 kHz to 6 GHz [r	equires Option UNJ]	
Frequency mi	nimum 100 kHz ²		
Frequency res	solution 0.01 Hz		
Frequency sw	vitching speed ³		
	Option 501-504	With Option UNJ	Option 506
	Freq. ⁴ Freq./Amp. ⁵	Freq. ⁴ Freq./Amp. ⁵	Freq. ⁴ Freq./Amp. ⁵
Digital m	odulation		<u> </u>
on	(< 35 ms) (< 49 ms)	(< 35 ms) (< 52 ms)	(< 41 ms) (< 57 ms)
off	(< 9 ms) (< 9 ms)	(< 9 ms (< 9 ms)	(< 16 ms (< 17 ms)
[For hops	s < 5 MHz within a band]		
Digital m	odulation		
on	(< 9 ms) (< 9 ms)	(< 9 ms) (< 9 ms)	(< 33 ms) (< 53 ms)
off	(< 9 ms) (< 9 ms)	(< 9 ms) (< 9 ms)	(< 12 ms) (< 14 ms)
Phase offset	Phase is adjustable in nominal 0.1° incr	e remotely [LAN, GPIB, RS rements	-232] or via front panel

Sweep modes

Operating modes	Frequency step, amplitude step and arbitrary list			
Dwell time	1 ms to 60 s			
Number of points	2 to 65,535			

Internal reference oscillator

ability ³		
	Standard	With Option UNJ or 1E5
Aging rate	< ±1 ppm/yr	< ±0.1 ppm/yr or
		$< \pm 0.0005$ ppm/day after 45 days
Temp [0 to 55° C]	(< ±1 ppm)	(< ±0.05 ppm)
Line voltage	(< ±0.1 ppm)	(< ±0.002 ppm)
Line voltage range	(+5% to -10%)	(+5% to –10%)
reference output		
Frequency	10 MHz	
Amplitude	4 dBm ±2 dB	
reference input requir	ements	
	Standard	With Option UNJ or 1E5
Frequency	1, 2, 5, 10 MHz ± 10 ppm	1, 2, 5, 10 MHz ±.2 ppm
Amplitude	–3.5 dBm to 20 dBm	
Input impedance	50 Ω	

1. The E4438C is available as a vector platform only. For analog models refer to the E4420B thru E4426B.

2. Performance below 250 kHz not guaranteed.

3. Parentheses denote typical performance.

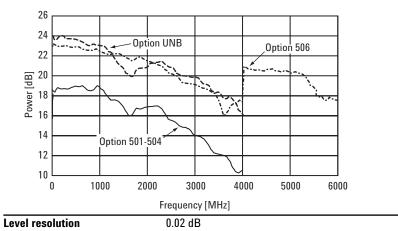
4. To within 0.1 ppm of final frequency above 250 MHz or within 100 Hz below 250 MHz.

5. Frequency switching time with the amplitude settled within $\pm 0.1~\text{dB}.$

Output power

Power			
	Option 501-504	With Option UNB	Option 506
250 kHz to 250 MHz	+11 to -136 dBm	+15 to –136 dBm	+12 to -136 dBm
> 250 MHz to 1 GHz	+13 to -136 dBm	+17 to –136 dBm	+14 to -136 dBm
> 1 to 3 GHz	+10 to -136 dBm	+16 to -136 dBm	+13 to –136 dBm
> 3 to 4 GHz	+7 to -136 dBm	+13 to –136 dBm	+10 to -136 dBm
> 4 to 6 GHz	N/A	N/A	+10 to -136 dBm

Typical maximum available power



Level range with Attenuator Hold active

•••	or rungo min micom				
		Option 501-504	With Option UNB	Option 506	
	250 kHz to 1 GHz	23 dB	27 dB	24 dB	
	> 1 to 3 GHz	20 dB	26 dB	23 dB	
	> 3 to 4 GHz	17 dB	23 dB	20 dB	
	> 4 to 6 GHz	N/A	N/A	20 dB	

Level accuracy [dB]

Option	501-504 ¹	,2
--------	----------------------	----

_	Power level			
	+7 to	–50 to	-110 to	< –127 dBm
	–50 dBm	–110 dBm	–127 dBm	
250 kHz to 2.0 GHz	±0.5	±0.5	±0.7	(±1.5)
2.2 to 3 GHz	±0.6	±0.6	±0.8	(±2.5)
3 to 4 GHz	±0.7	±0.7	±0.9	(±2.5)

With Option UNB^{2,3}

_	Power level			
	+10 to	–50 to	-110 to	< –127 dBm
	–50 dBm	–110 dBm	–127 dBm	
250 kHz to 2.0 GHz	±0.5	±0.7	±0.8	(±1.5)
2.2 to 3 GHz	±0.6	±0.8	±1.0	(±2.5)
3 to 4 GHz	±0.8	±0.9	±1.3	(±2.5)

- Quoted specifications for 23 °C ± 5 °C. Accuracy degrades by less than 0.03 dB/°C over full temperature range. Accuracy degrades by 0.3 dB above +7 dBm, and by 0.8 dB above +10 dBm.
- 2. Parentheses denote typical performance.
- Quoted specifications for 23 °C ± 5 °C. Accuracy degrades by less than 0.03 dB/°C over full temperature range. Accuracy degrades by 0.2 dB above +10 dBm, and by 0.8 dB above +13 dBm.
- 4. Quoted specifications for 23 °C \pm 5 °C. Accuracy degrades by less than 0.02 dB/°C over full temperature range. Accuracy degrades by 0.2 dB above +7 dBm.

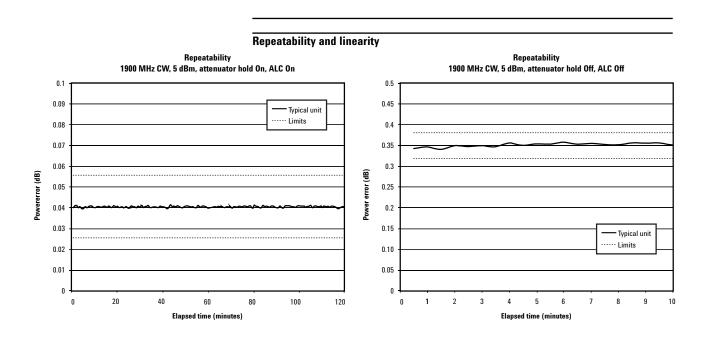
h

Option 506 ^{2, 4}				
_		Power l	evel	
	+7 to	–50 to	–110 to	< –127 dBm
	–50 dBm	–110 dBm	–127 dBm	
250 kHz to 2.0 GHz	±0.6	±0.8	±0.8	(±1.5)
2.2 to 3 GHz	±0.6	±0.8	±1.0	(±2.5)
3 to 4 GHz	±0.8	±0.9	±1.5	(±2.5)
4 to 6 GHz	±0.8	±0.9	(±1.5)	

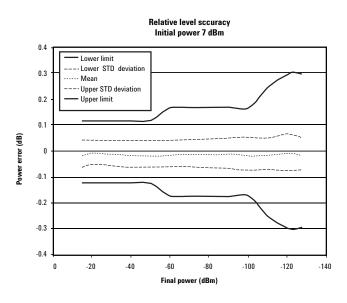
•	vith digital modulation	-	ative to CW]	
Conditions:	L		, 1	
	if using I/Q inputs,	$\sqrt{1^2 + U^2} = 0.5 V$	rms, nominal] ¹	
Level accuracy v	vith ALC on			
$\pi/4$ DQPSK	or QPSK formats			
Conditions:	With raised cosine	or root-raised co	sine filter and $a \ge 0$.35;
	with 10 kHz \leq symbols	bol rate ≤ 1 MHz;	at RF freq \geq 25 MHz	Z;
	power \leq max speci	fied –3 dB		
	Option 501-504			
	±0.15 dB	,		
Constant an	plitude formats [FSK	, GMSK, etc]		
	Option 501-504	-		
	±0.1 dB			
evel accuracy v	vith ALC off $1, 2$ (±0.1	15 dB) (relative to	o Al C on]	
Conditions:			executed, with burs	st off.
Level switching	speed ¹			
Ū	-	Option 501-504	With Option UNB	Option 506
Normal oper	ration [ALC on]	(< 15 ms)	(< 21 ms)	(< 21 ms)
	power search manual	l (< 83 ms)	(< 95 ms)	(< 95 ms)
When using	power search auto	(< 103 ms)		(< 119 ms)
-				

^{1.} Parentheses denote typical performance.

^{2.} When applying external I/Q signals with ALC off, output level will vary directly with I/Q input level.

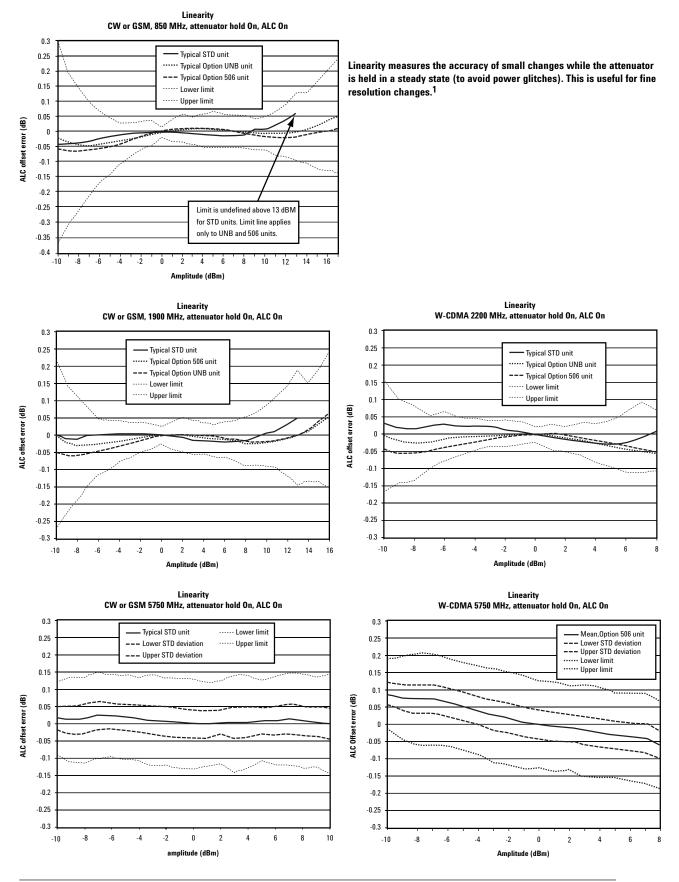


Repeatability measures the ability of the instrument to return to a given power setting after a random excursion to any other frequency and power setting. It is a relative measurement that reflects the difference in dB between the maximum and minimum power readings for a given setting over a specific time interval. It should not be confused with absolute power accuracy, which is measured in dBm.¹



Relative level accuracy measures the accuracy of a step change from any power level to any other power level. This is useful for large changes (i.e. 5 dB steps).¹

1. Repeatability and relative level accuracy are typical for all frequency ranges.



^{1.} Repeatability and relative level accuracy are typical for all frequency ranges.

Spectral purity

SSB Phase noise [at]	SB Phase noise [at 20 kHz offset] ¹				
	Standard	With Option UNJ			
at 500 MHz	(< −124 dBc/Hz)	< –137 dBc/Hz, (< –138 dBc/Hz)			
at 1 GHz	(< –118 dBc/Hz)	<-133 dBc/Hz, (<-138 dBc/Hz)			
at 2 GHz	(< –112 dBc/Hz)	<-126 dBc/Hz, (<-128 dBc/Hz)			
at 3 GHz	(< –106 dBc∕Hz)	< –124 dBc/Hz, (< –125 dBc/Hz)			
at 4 GHz	(< –106 dBc∕Hz)	< –121 dBc/Hz, (< –122 dBc/Hz)			
at 6 GHz	N/A	< –115 dBc/Hz, (< –117 dBc/Hz)			
Residual FM ¹ [CW m	ode, 0.3 to 3 kHz BW, CCI				
Option UNJ	< N x 1 Hz (< N x 0.5 Hz) ²			
Standard					
Phase nois	e mode 1 🛛 < N x 2 Hz				
Phase nois	e mode 2 < N x 4 Hz				

Harmonics^{1, 3} [output level \leq +4 dBm, \leq +7.5 dBm Option UNB, \leq +4.5 dBm Option 506] < -30 dBc above 1 GHz, (< -30 dBc 1 GHz and below)

Nonharmonics^{1, 4} [\leq +7 dBm output level, \leq +4 dBm Option 506]

	Standard ⁵	With Opt	ion UNJ ⁶	
	> 3 kHz offset	> 10 kHz offset	> 3 kHz < 10 kHz offset	> 10kHz offset
250 kHz to 250 MHz	<53 dBc (<68 dBc)	(< –58 dBc)	<65 dBc	(< –58 dBc)
250 MHz to 500 MHz	<	(<81 dBc)	<80 dBc	< –80 dBc
500 MHz to 1 GHz	<53 dBc (<68 dBc)	(< –75 dBc)	<80 dBc	< –80 dBc
1 to 2 GHz	<47 dBc (<62 dBc)	(<69 dBc)	<74 dBc	< –74 dBc
2 to 4 GHz	< -41 dBc (< -56 dBc)	(<63 dBc)	<68 dBc	< –68 dBc
4 to 6 GHz	N/A N/A	N/A	<62 dBc	<62 dBc

Subharmonics

		Standard	With Option UN.	J
≤1 GHz		None	None	
>1 GHz		<-40 dBc	None	
Jitter in µUI ^{1, 7, 8}				
Carrier	SONET/SDH	rms jitte	er Standard	With option UNJ
frequency	data rates	bandwid	lth (μUI rms)	(µUI rms)
155 MHz	155 MB/s	100 Hz to 1.5	5 MHz (359)	(78)
622 MHz	622 MB/s	1 kHz to 5	MHz (158)	(46)
2.488 GHz	2488 MB/s	5 kHz to 15	MHz (384)	(74)
Jitter in seconds ^{1,}	7, 8			
Carrier	SONET/SDH	rms jitte	er Standard	With option UNJ
frequency	data rates	bandwid	th	
155 MHz	155 MB/s	100 Hz to 1.5	5 MHz (2.4 ps)	(0.6 ps)
622 MHz	622 MB/s	1 kHz to 5	MHz (255 fs)	(74 fs)
2.488 GHz	2488 MB/s	5 kHz to 15	MHz (155 fs)	(30 fs)

1. Parentheses denote typical performance.

3. Harmonic performance outside the operating range of the instrument is typical.

4. Spurs outside the operating range of the instrument are not specified.

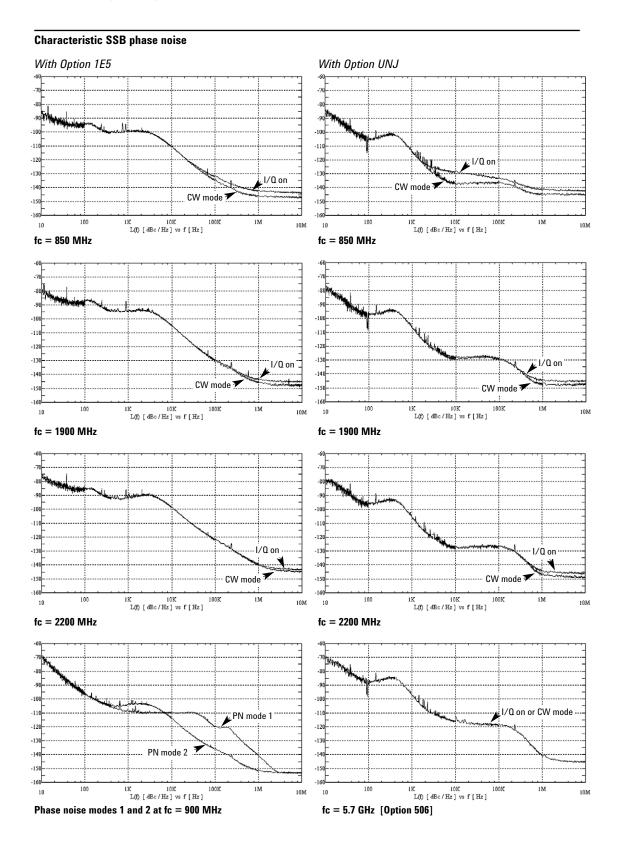
5. Specifications apply for FM deviations < 100 kHz and are not valid on ΦM. For non-constant amplitude formats, unspecified spur levels occur up to the second harmonic of the baseband rate.

6. Specifications apply for CW mode only.

7. Calculated from phase noise performance in CW mode only at -2.5 dBm for standard instruments, -0.5 dBm with Option 506, and +2.5 dBm with Option UNB.

8. For other frequencies, data rates, or bandwidths, please contact your sales representative.

^{2.} Refer to frequency bands on page 12 for N values.



Frequency bands

Band	Frequency range	N number
1	250 kHz to \leq 250 MHz	1
2	> 250 MHz to \leq 500 MHz	0.5
3	$>$ 500 MHz to \leq 1GHz	1
4	> 1 to ≤ 2 GHz	2
5	> 2 to ≤ 4 GHz	4
6	$>$ 4 to \leq 6 GHz	8

Frequency modulation^{1,2}

Maximum deviation ³			
	<i>Standard</i> N x 8 MHz	<i>With Optior</i> N x 1 MHz	ו UNJ
Resolution	0.1% of devi whichever is	ation or 1 Hz, s greater	
Modulation frequency	rate ⁴ [deviatio	on = 100 kHz]	
Coupling	1 dB bandw	idth	3 dB bandwidth
FM path 1[DC]	DC to 100 kl	Hz	(DC to 10 MHz)
FM path 2 [DC]	DC to 100 kl	Hz	(DC to 0.9 MHz)
FM path 1 [AC]	20 Hz to 100) kHz	(5 Hz to 10 MHz)
FM path 2 [AC]	20 Hz to 100) kHz	(5 Hz to 0.9 MHz)
Deviation accuracy ³ [1	kHz rate, devia	ntion < N x 100	kHz]
	< ± 3.5% of	FM deviation	+ 20 Hz
Carrier frequency accu			
		t deviation +	(N X I H2)
Distortion ³ [1 kHz rate,	dev.= N x 100 < 1%	kHz]	
FM using external inpu	its 1 or 2		
Sensitivity	1 V _{peak} for in	ndicated devia	ation
Input impedance	50 Ω , nomin	nal	
•	imited to a ma	ximum rate of	lly for composite modulation. 1 MHz. The FM 2 path must be

^{1.} All analog performance above 4 GHz is typical.

^{2.} For non-Option UNJ units, specifications apply in phase noise mode 2 [default].

^{3.} Refer to frequency bands on this page to compute specifications.

^{4.} Parentheses denote typical performance.

^{5.} At the calibrated deviation and carrier frequency, within 5 °C of ambient temperature at time of calibration.

Phase modulation 1, 2

Resolution	0.1% of set d	eviation	
Modulation freque	ency response ^{3, 4}		
Standard			
	Maximum	Allowable	rates [3 dB BW]
Mode	deviation	ΦM path 1	ΦM path 2
Normal BW	N x 80 rad	DC to 100 kHz	DC to 100 kHz
High BW ⁶	N x 8 rad	(DC to 1 MHz)	(DC to 0.9 MHz)
	N x 1.6 rad	(DC to 10 MHz)	(DC to 0.9 MHz)
With Option UNJ			
	Maximum	Allowable	rates [3 dB BW]
Mode	deviation	ΦM path 1	ΦM path 2
Normal BW	N x 10 radians	DC to 100 kHz	DC to 100 kHz
High BW	N x 1 radians	(DC to 1 MHz)	(DC to 0.9 MHz)
Distortion ³ [1 kHz Option	UNJ models, Norma < 1%	on + 0.01 radians radians on standard m	odel, < 10 N radians on
$\Phi \mathbf{M}$ using externa	l inputs 1 or 2		
Sensitivity	1 V _{peak} for in	1 V _{peak} for indicated deviation	
Input impedar	nce 50 Ω , nominal		
Paths	modulation.	ΦM path 1 and ΦM path 2 are summed internally for composite modulation. The ΦM 2 path is limited to a maximum rate of 1 MHz. ΦM path 2 must be set to a deviation less than the ΦN path 1.	

Range	0 to 100%
Paths	ΦM path 1 and ΦM path 2 are summed internally for composite modulation. The ΦM 2 path is limited to a maximum rate of 1 MHz. ΦM path 2 must be set to a deviation less than the ΦM path 1.
Input impedance	50 Ω , nominal

Range	0 to 100%			
Resolution	0.1%			
Rates [3 dB bandv	<i>v</i> idth]			
DC coupled	0 to 10 kHz			
AC coupled	10 Hz to 10 kHz			
Accuracy ^{4, 7}	1 kHz rate < ±(6% of se	etting +1%)		
Distortion ^{4, 7} [1 kH	Iz rate, THD]			
	Option 501-504/Option UNJ	Option 506		
30% AM	< 1.5%	< 1.5%		
90% AM	(< 4%)	(< 5%)		
AM using externa	l inputs 1 or 2			
Sensitivity	1 V _{peak} to achieve indicate	ed depth		
Input impeda	nce 50 Ω , nominal	50 Ω , nominal		
Paths	AM path 1 and AM path 2 composite modulation.	are summed internally for		

1. All analog performance above 4 GHz is typical.

2. For non-Option UNJ units, specifications apply in phase noise mode 2 [default].

3. Refer to frequency bands on page 12 for N.

Amplitude modulation^{1, 6}

[fc > 500 kHz]

4. Parentheses denote typical performance.

5. Bandwidth is automatically selected based on deviation.

6. AM is typical above 3 GHz or if wideband AM or I/Q modulation is simultaneously enabled.

7. Peak envelope power of AM must be 3 dB less than maximum output power below 250 MHz.

Wideband AM

Pulse modulation

Rates [1 dB bandwidth]	
ALC on ALC off	(400 Hz to 40 MHz) (DC to 40 MHz)
Wideband AM using ex	ternal I input only
Sensitivity	0.5 V = 100%
Input impedance	50 Ω , nominal
On/off ratio ¹	
≤ 4 GHz > 4 GHz	> 80 dB (> 64 dB)
-	
Rise/fall times ¹	(150 ns)
Minimum width ¹	
ALC on	(2 μs)
ALC off	(0.4 μs)
Pulse repetition frequer	
ALC on	(10 Hz to 250 kHz)
ALC off	(DC to 1.0 MHz)
	ive to CW at \leq 4 dBm standard, \leq 7.5 dBm Option UNB dBm Option 506] (< ±1 dB)
Pulse modulation using	external inputs
Input voltage	
RF on	> +0.5 V, nominal
RF off	< +0.5 V, nominal
Input impedance	50 Ω , nominal
Internal pulse generato	r
Square wave rate Pulse	0.1 Hz to 20 kHz
Period	8 µs to 30 seconds
	A up to 20 papando
Width Resolution	4 μs to 30 seconds 2 μs

1. Parentheses denote typical performance.

2. With ALC off, specifications apply after the execution of power search. With ALC on, specifications apply for pulse repetition rates \leq 10 kHz and pulse widths \geq 5 μ s.

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Internal modulation source

Provides modulating signal for FM, AM, pulse and phase modulation signals, and provides LF output source for basic function generator capability.

Waveforms	Sine, square, ramp, triangle, pulse, noise	
Rate range		
Sine	0.1 Hz to 100 kHz	
Square, ramp, triangle	0.1 Hz to 20 kHz	
Resolution	0.1 Hz	
Frequency accuracy	Same as RF reference source	
Swept sine mode [frequency, pl	nase continuous]	
Operating modes	Triggered or continuous sweeps	
Frequency range	0.1 Hz to 100 kHz	
Sweep time	1 ms to 65 sec	
Resolution	1 ms	
Dual sinewave mode		
Frequency range	0.1 Hz to 100 kHz	
Amplitude ratio	0 to 100%	
Amplitude ratio resolution	0.1%	
LF audio out mode		
Amplitude	0 to 2.5 V $_{\text{peak}}$ into 50 Ω	
Output impedance	50 Ω nominal	

External modulation inputs

Modulation types Ext 1 Ext 2

FM, $\Phi \text{M},$ AM, pulse, and burst envelope FM, $\Phi \text{M},$ AM, and pulse

High/Low Indicator [100 Hz to 10 MHz BW, AC coupled inputs only]. Activated when input level error exceeds 3% [nominal].

Input voltage			
RF On	0 V		
RF Off	-1.0 V		
Linear control range	0 to -1 V		
On/off ratio ¹			
Condition: V _{in} below	–1.05 V		
	\leq 4 GHz	> 75 dB	
	> 4 GHz	(> 64 dB)	
Condition: With recta	ingular input		
	(< 2 μs)		
Minimum burst repetition			
Minimum burst repetition ALC on			
	frequency ¹		
ALC on	frequency ¹ (10 Hz)		

Composite modulation

External burst envelope

AM, FM, and Φ M each consist of two modulation paths which are summed internally for composite modulation. The modulation sources may be any two of the following: Internal, External 1, External 2.

Simultaneous modulation

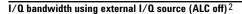
Multiple modulation types may be simultaneously enabled. For example, W-CDMA, AM, and FM can run concurrently and all will affect the output RF. This is useful for simulating signal impairments. There are some exceptions: FM and Φ M cannot be combined; AM and Burst envelope cannot be combined; Wideband AM and internal I/Q cannot be combined. Two modulation types cannot be generated simultaneously by the same modulation source.

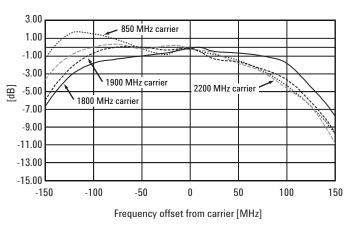
1. Parentheses denote typical performance.

I/Q modulation bandwidth

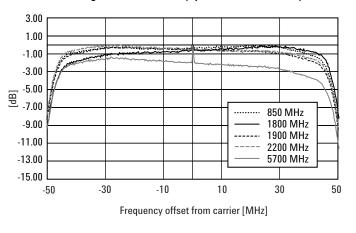
I/Q inputs

Input impedance Full scale input¹ $\frac{50 \ \Omega \text{ or } 600 \ \Omega}{\sqrt{I^2 + Q^2}} = 0.5 \ V_{rms}$





I/Q bandwidth using internal I/Q source (Options 001, 002, 601, 602)



2. Tarentilooco achoto typical performance.

^{1.} The optimum I/Q input level is $\sqrt{1^2+Q^2} = 0.5 V_{rms}$. I/Q drive level affects EVM, origin offset, spectral regrowth, and noise floor. Typically, level accuracy with ALC on will be maintained with drive levels between 0.25 and 1.0 V_{rms}.

^{2.} Parentheses denote typical performance.

I/Q adjustments

Source	Parameter	Range
I/Q baseband inputs	Impedance	50 or 600 Ω
	l offset [600 Ω only]	
	Q offset [600 Ω only]	± 5 V
I/Q baseband outputs	I/Q offset adjustment	
	I/Q offset resolution	1 mV ± 4 dB
	I/Q gain balance I/Q attenuation	1 to 40 dB
	I/Q low pass filter	40 MHz, through
RF output	I/Q offset adjustment	+ 50%
in output	I/Q gain balance	± 4 dB
	I/Q attenuation	0 to 40 dB
	I/Q quad skew	
	[≤ 3.3 GHz]	± 10°
	[> 3.3 GHz]	± 5°
	I/Q low pass filter	2.1 MHz, 40 MHz, through
I/Q baseband outputs ¹		
Differential outputs	I, I, Q, Q	
Single ended	Ι, Ο	
Frequency range	DC to 40 MHz [with sinewave]	
Output voltage into 50 Ω	•	P) [with sinewave]
Output impedance	50 Ω nom	ninal

Baseband generator

[arbitrary waveform mode] [Option 601 or 602]

Channels	2 [l and Q]			
Resolution	16 bits [1/65,536]			
Arbitrary waveform memory				
Maximum playback capacity	8 megasamples (MSa)/channel [Option 601]			
	64 MSa/channel [Option 602]			
Maximum storage capacity	1 GSa [Option 005]			
	3 MSa [Standard]			
Waveform segments				
Segment length	60 samples to 8 or 64 MSa			
Maximum number of segments	1,024 [8 MSa volatile memory]			
	8,192 [64 MSa volatile memory]			
Minimum memory allocation	256 samples or 1 KB blocks			
Waveform sequences				
Maximum total number of segme	ent files			
stored in the non-volatile				
file system	16,384			
Sequencing	Continuously repeating			
Maximum number of sequences	16,384 [shared with number of segments]			
Maximum segments/sequence	32,768 [including nested segments]			
Maximum segment repetitions	65,536			

Clock	
Sample rate	1 Hz to 100 MHz
Resolution	0.001 Hz
Accuracy	Same as timebase +2 ⁻⁴² [in non-integer applications
Baseband filters	
40 MHz	used for spur reduction
2.1 MHz	used for ACPR reduction
Through	used for maximum bandwidth
Reconstruction filter: [fixed]	
50 MHz	[used for all symbol rates]
Baseband spectral purity ¹	
[full scale sinewave]	
Harmonic distortion	
100 kHz to 2 MHz	(<−65 dBc)
Phase noise	(< -127 dBc/Hz)
[baseband output of 10 MHz s	
IM performance	(<-74 dB)
[two sinewaves at 950 kHz and	a 1050 kmz al basebanaj
Triggers	Continuous simple noted comments during
Types Source	Continuous, single, gated, segment advance Trigger key, external, remote [LAN, GPIB, RS-232]
External polarity	Negative, positive
External polarity	Negative, positive
External delay time	10 ns to /0 sec plus latency
External delay time External delay resolution	10 ns to 40 sec plus latency 10 ns
External delay resolution	
External delay resolution Markers	10 ns
External delay resolution Markers [Markers are defined in a segment	10 ns during the waveform generation process, or from the
External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also	10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.]
External delay resolution Markers [Markers are defined in a segment	10 ns during the waveform generation process, or from the
External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers	10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive
External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity	10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4
External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier	10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz
External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers	10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4
External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier	10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type]
External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier]	10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz
External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier] Power offset [per carrier]	10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz
External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier] Power offset [per carrier] Modulation	10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz 0 dB to -40 dB
External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier] Power offset [per carrier] Modulation	10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz 0 dB to -40 dB BPSK, QPSK, 0QPSK, π/4DQPSK, 8PSK,
External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier] Power offset [per carrier] Modulation PSK	10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz 0 dB to -40 dB BPSK, QPSK, 0QPSK, π/4DQPSK, 8PSK, 16PSK, D8PSK
External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier] Power offset [per carrier] Modulation PSK QAM	10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz 0 dB to -40 dB BPSK, QPSK, 0QPSK, π/4DQPSK, 8PSK, 16PSK, D8PSK 4, 16, 32, 64, 128, 256
External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier] Power offset [per carrier] Modulation PSK QAM FSK MSK	10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz 0 dB to -40 dB BPSK, QPSK, 0QPSK, π/4DQPSK, 8PSK, 16PSK, D8PSK 4, 16, 32, 64, 128, 256
External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier] Power offset [per carrier] Modulation PSK QAM FSK MSK Data Multitone	10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz 0 dB to -40 dB BPSK, QPSK, 0QPSK, π/4DQPSK, 8PSK, 16PSK, D8PSK 4, 16, 32, 64, 128, 256 Selectable: 2, 4, 8, 16 Random ONLY
External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier] Power offset [per carrier] Modulation PSK QAM FSK MSK Data	10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz 0 dB to -40 dB BPSK, QPSK, 0QPSK, π/4DQPSK, 8PSK, 16PSK, D8PSK 4, 16, 32, 64, 128, 256 Selectable: 2, 4, 8, 16
External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier] Power offset [per carrier] Modulation PSK QAM FSK MSK Data Multitone	10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz 0 dB to -40 dB BPSK, QPSK, 0QPSK, π/4DQPSK, 8PSK, 16PSK, D8PSK 4, 16, 32, 64, 128, 256 Selectable: 2, 4, 8, 16 Random ONLY

^{1.} Parentheses denote typical performance.

Baseband generator

[real-time mode] [Option 601 or 602]

	types [custom format]						
PSK	BPSK, QPSK, OQPSK,						
MSK	User-defined phase offset from 0 to 100°						
0AM	4, 16, 32, 64, 128, 256		24584				
FSK	Selectable: 2, 4, 8, 16 level symmetric, C4FM						
	User defined: Custom map of up to 16 deviation levels						
	Symbol rate	Maximum dev	viation				
	< 5 MHz	4 times symbol	ol rate				
	> 5 MHz, < 50 MHz	20 MHz					
	Resolution: 0.1 Hz						
/ Q Custom	map of 256 unique value	es					
IR filter							
Selectable	Nyquist, root Nyquist,		gular, Apco 25				
	<i>a</i> : 0 to 1, B _b T: 0.1 to 1						
Custom FIR	16-bit resolution, up to	o 64 symbols long	, automatically resampled t				
	1024 coefficients [max	x]					
	> 32 to 64 symbol filte	er: symbol rate \leq 1	2.5 MHz				
	> 16 to 32 symbol filte	er: symbol rate ≤ 2	25 MHz				
	Internal filters switch	to 16 tap when sy	/mbol rate is				
	between 25 and 50 M	Hz					
Symbol roto							
Symbol rate							
•	serial data, symbol rate is	s adjustable					
For external s	•	•	50 Mbits/sec				
For external s	serial data, symbol rate is mbols/sec to a maximur	•	50 Mbits/sec #bits/symbol				
For external s from 1000 sy	mbols/sec to a maximur	n symbol rate of	#bits/symbol				
For external s from 1000 sy For internally	mbols/sec to a maximur generated data, symbol	n symbol rate of rate is adjustable	#bits/symbol from 1000 symbols/sec to				
For external s from 1000 sy For internally 50 Msymbols	mbols/sec to a maximur generated data, symbol	n symbol rate of rate is adjustable	#bits/symbol				
For external s from 1000 sy For internally 50 Msymbols	mbols/sec to a maximur generated data, symbol s/sec. and a maximum of high symbol rates.	n symbol rate of rate is adjustable	#bits/symbol from 1000 symbols/sec to				
For external s from 1000 sy For internally 50 Msymbols degraded at l	mbols/sec to a maximur generated data, symbol s/sec. and a maximum of high symbol rates.	n symbol rate of rate is adjustable f 8 bits per symbo	#bits/symbol from 1000 symbols/sec to I. Modulation quality may b				
For external s from 1000 sy For internally 50 Msymbols degraded at l	mbols/sec to a maximur generated data, symbol s/sec. and a maximum of high symbol rates. Ice frequency Data clock can be pha	n symbol rate of rate is adjustable f 8 bits per symbo ise locked to an e	#bits/symbol from 1000 symbols/sec to I. Modulation quality may b xternal reference.				
For external s from 1000 sy For internally 50 Msymbols degraded at l	mbols/sec to a maximur generated data, symbol s/sec. and a maximum of high symbol rates. Ice frequency Data clock can be pha	n symbol rate of rate is adjustable f 8 bits per symbo se locked to an e kHz to 100 MHz in	#bits/symbol from 1000 symbols/sec to I. Modulation quality may b xternal reference. n W-CDMA and cdma2000 ^{1,}				
For external s from 1000 sy For internally 50 Msymbols degraded at I Baseband referen Input	mbols/sec to a maximum generated data, symbol s/sec. and a maximum of high symbol rates. Ice frequency Data clock can be pha 13 MHz for GSM, 250 ECL, CMOS, TTL comp	n symbol rate of rate is adjustable f 8 bits per symbo se locked to an e kHz to 100 MHz in	#bits/symbol from 1000 symbols/sec to I. Modulation quality may b xternal reference. n W-CDMA and cdma2000 ^{1,}				
For external s from 1000 sy For internally 50 Msymbols degraded at l Baseband referen	mbols/sec to a maximum generated data, symbol s/sec. and a maximum of high symbol rates. Ice frequency Data clock can be pha 13 MHz for GSM, 250 ECL, CMOS, TTL comp	n symbol rate of rate is adjustable f 8 bits per symbo se locked to an e kHz to 100 MHz in	#bits/symbol from 1000 symbols/sec to I. Modulation quality may b xternal reference. n W-CDMA and cdma2000 ^{1,}				

2. When used, this baseband reference is independent of the 10 MHz RF reference.

^{1.} Performance below 1 MHz not specified.

Data types		
	enerated data	
, .	andom patterns	PN9, PN11, PN15, PN20, PN23
	a sequence	Any 4-bit sequence
		Other fixed patterns
Direct-patte	rn RAM (PRAM)	· · ·
Max size	Option 601	8 Mbits
	Option 602	64 Mbits
		[each bit uses an entire sample space]
Use	Non-standard framing	
User file		
Max size	Option 601	800 kB
	Option 602	6.4 MB
Use	Continuous modulation or i	nternally generated TDMA standard
Externally g	enerated data	
Туре	Serial data	
Inputs	Data, bit clock, symbol syn	C
	Accepts data rates ±5% of	specified data rate
Internal burst sh	ape control	
Varies with	standards and bit rates	
Rise/fall	time range	Up to 30 bits
Rise/fall	delay range	0 to 63.5 bits

Specifications for Signal Personality Characteristics

3GPP W-CDMA [arbitrary waveform mode ²] [Option 400]	Error vector magnitude 1[1.8 GHz < f_c < 2.2 GHz, root Nyquist filters, 40 MHz baseband filter, EVM optimization mode3.84 Mcps chip rate, \leq 4 dBm, \leq 7 dBm with Option UNB]1 DPCH \leq 1.8%, (0.9%)
	Level accuracy [relative to CW at 800, 900, 1800, 1900, 2200 MHz] ¹ [\leq 2.5 dBm standard, 7.5 dBm for Option UNB, and 4.5 dBm for Option 506] ±0.7 dB (±0.35 dB)
	Adjacent channel leakage ratio1 $[1.8 \text{ GHz} < f_c < 2.2 \text{ GHz}, default W-CDMA filters, 3.84 Mcps chip rate,\leq 0 \text{ dBm Option UNB}, \leq -2 \text{ dBm Option 506}, \leq -3 \text{ dBm standard in Optimize ADJ mode}]1 DPCH-65 dBc (-67 dBc)Test Model 1-63 dBc (-66 dBc)+ 64 DPCH$
	Alternate channel leakage ratio1 $[1.8 \text{ GHz} < f_c < 2.2 \text{ GHz}, \text{ default W-CDMA filters}, 3.84 \text{ Mcps chip rate},$

1. Parentheses denote typical performance.

2. Valid for $23^{\circ} \pm 5^{\circ}$ C.

IS-95 CDMA

[arbitrary waveform mode¹] [Option 401]

Spurious emissions

[dBc, IS-95 modified filter with equalizer and amplitude = \leq -5 dBm standard, \leq -3 dBm for Option 506, \leq 0 dBm for Option UNB] 2

	0.885 to	1.25 MHz	1.25 to	1.98 MHz	1.98 to 5 MHz	
Frequencies/offsets	Standard	Option 506	Standard	Option 506	Standard	Option 506
Reverse						
30 – 200 MHz	(-74)	(74)	(–77)	(-77)	(-77)	(–77)
700 – 1000 MHz	-73 (-77)	-73 (-77)	(81)	(81)	(—85)	(—85)
>1000 - 2000 MHz	-76 (-79)	-75 (-79)	(—83)	(—83)	(—85)	(—85)
9/64 channels						
30 – 200 MHz	(70)	(—70)	(–73)	(73)	(76)	(76)
700 – 1000 MHz	-73 (-76)	-73 (-76)	(79)	(79)	(82)	(82)
>1000 – 2000 MHz	-72 (-76)	-71 (-76)	(—79)	(—79)	(—82)	(—82)
Bho ¹ [< 4 dBm stand	lard and Op	tion 506, or < 7	7 dBm Onti	on UNB, IS-	95 filter. <	2 GHz]

Rho¹[\leq 4 dBm standard and Option 506, or \leq 7 dBm Option UNB, IS-95 filter, \leq 2 GHz] $\rho \geq$ 0.9992 (.9998)

cdma2000

[arbitrary waveform mode] [Option 401]

Spurious emissions

[dBc, IS-95 modified filter with equalizer and amplitude = \leq -5 dBm standard, \leq -3 dBm for Option 506, \leq 0 dBm for Option UNB]

	Offsets from center of carrier							
Frequencies/offsets	2.135 to 2.50 MHz	2.50 to 3.23 MHz	3.23 to 10 MHz					
Forward 9 channel, SR3/multi-carrier ^{1, 3}								
30 – 200 MHz	(—70)	(- 69)	(69)					
700 – 1000 MHz	(—75)	(—74)	(77)					
>1000 – 2000 MHz	: (—75)	(74)	(-77)					
	0	Offsets from center of carri	er					
Frequencies/offsets	2.655 to 3.75 MHz	3.75 to 5.94 MHz	5.94 to 10 MHz					
Forward 9 channel, S	R3/DS ^{1, 4}							
30 – 200 MHz	(—76)	(78)	(—75)					
700 – 1000 MHz	(—80)	(83)	(—85)					
>1000 – 2000 MHz	: (—80)	(83)	(85)					
Reverse 5 channel, S	R3/DS ^{1, 3}							
30 – 200 MHz	(—78)	(78)	(—75)					
700 – 1000 MHz	(82)	(83)	(—85)					
>1000 - 2000 MHz	z (–82)	(83)	(—85)					
F	J.,							

Error vector magnitude

[\leq 4 dBm standard and Option 506, \leq 7 dBm for Option UNB] [825 to 2100 MHz, SR3 pilot, IS-95 filter, which is optimized for EVM]¹

EVM ≤ 2.1%, (≤ 1.5%)

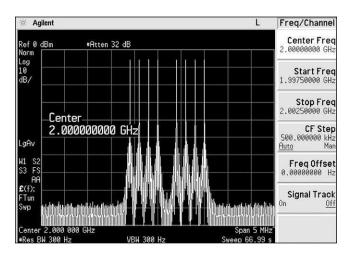
1. Valid for $23^{\circ} \pm 5^{\circ}$ C.

- 2. Parentheses denote typical performance.
- 3. Measurements performed with 30 kHz BW, relative to power in one carrier.
- 4. Measurements performed with 30 kHz BW, relative to total power.

Enhanced multitone¹

[arbitrary waveform mode] [Option 408]

Number of tones 2 to 1024 Tone spacing 1 kHz to 50 MHz, limited by 80 MHz I/Q bandwidth Tone power (relative) 0 to -50 dB Phase distribution Fixed, random or parabolic Suppression level -50 to -90 dBc, depending on number of tones and available calibration time. Expected suppression = 80 dBc -10 log [N/8], where N is the number of tones Calibration interval 8 hours Calibration time 10 minutes (8 tones, -80 dBc suppression) Temperature stability 1 dB/°C (typical for IMD products) 5 dB/°C (worst case for L0 feedthrough and unbalanced images)		
Tone power (relative) 0 to -50 dB Phase distribution Fixed, random or parabolic Suppression level -50 to -90 dBc, depending on number of tones and available calibration time. Expected suppression = 80 dBc -10 log [N/8], where N is the number of tones Calibration interval 8 hours Calibration time 10 minutes (8 tones, -80 dBc suppression) Temperature stability 1 dB/°C (typical for IMD products) 5 dB/°C (worst case for L0 feedthrough and unbalanced	Number of tones	2 to 1024
Phase distribution Fixed, random or parabolic Suppression level -50 to -90 dBc, depending on number of tones and available calibration time. Expected suppression = 80 dBc -10 log [N/8], where N is the number of tones Calibration interval 8 hours Calibration time 10 minutes (8 tones, -80 dBc suppression) Temperature stability 1 dB/°C (typical for IMD products) 5 dB/°C (worst case for L0 feedthrough and unbalanced	Tone spacing	1 kHz to 50 MHz, limited by 80 MHz I/Q bandwidth
Suppression level -50 to -90 dBc, depending on number of tones and available calibration time. Expected suppression = 80 dBc -10 log [N/8], where N is the number of tones Calibration interval 8 hours Calibration time 10 minutes (8 tones, -80 dBc suppression) Temperature stability 1 dB/°C (typical for IMD products) 5 dB/°C (worst case for LO feedthrough and unbalanced	Tone power (relative)	0 to -50 dB
and available calibration time. Expected suppression = 80 dBc -10 log [N/8], where N is the number of tones Calibration interval 8 hours Calibration time 10 minutes (8 tones, -80 dBc suppression) Temperature stability 1 dB/°C (typical for IMD products) 5 dB/°C (worst case for LO feedthrough and unbalanced	Phase distribution	Fixed, random or parabolic
Calibration time 10 minutes (8 tones, -80 dBc suppression) Temperature stability 1 dB/°C (typical for IMD products) 5 dB/°C (worst case for LO feedthrough and unbalanced	Suppression level	and available calibration time. Expected suppression = 80 dBc –10 log [N/8],
Temperature stability 1 dB/°C (typical for IMD products) 5 dB/°C (worst case for LO feedthrough and unbalanced	Calibration interval	8 hours
(worst case for LO feedthrough and unbalanced	Calibration time	10 minutes (8 tones, –80 dBc suppression)
	Temperature stability	(worst case for LO feedthrough and unbalanced



Enhanced multitone signal with correction applied

Crest factor [output power set at least 16 dB below maximum power] > 16 dB						
Randomness	89 bit pseudo-random generation, repetition period 3 x 10 ⁹ years					
Carrier to noise ratio	Magnitude error \leq 0.2 dB at baseband I/Q outputs.					

AWGN

[real-time mode] [Option 403]

1. All values typical.

802.11 WLAN

[arbitrary waveform mode] [Option 417]¹

EVM

(< 1%, -40 dB)

The EVM was measured with an 89641A vector signal analyzer with Option B7R.

Instrument and software settings listed below.

ftware settings		Source settings	
Data rate	54 Mbps	Frequency	5.8/2.4/0.9 GHz
Modulation	64 QAM	Output power	≤–1 dBm
Encoder	3/4 rate	Reconstruction filter	thru
Scrambler	active	ALC	On
interleaver	active	RF blanking	Off
Scrambler initialization	5D	Modulator Atten	8 to 10 dB
Support carrier setup	All channels a	active	
Idle interval	100 µS	89641A settings	
OSR	≥2	Frequency	5.8/2.4/0.9 GHz
Window length	≥8	Span	20 MHz
Data type	PN15	Range	optimal
Data length	1024	RMS video average	20

802.11a spectral mask typical performance

(0 dbm, at 5.805 GHz, OSR: 4, window length: 16)

10.00	00dBm		10 III		ctrum		1	<u> </u>			T	-
dB/					(water	Nerrora					F	
				_	٧		Þ	\downarrow		-	F	
			_	mark			À.	\square	~		ŧ	_
		#179.110.45pt=43j.45	1					WIG WAY		partmetic		
	Acres 11/2	11.0.04.44				7	+	-			T ALATA	45-44
	5.775	GHz		Abs Li	nit	Rel Limi	t			5.8	75 (ЭHz
Total Pw Start(Hz	r: -0.36) St	idBm op(Hz)	/ 22.000 Meas B	0500000000	10.000	PSD Re Lowe		5V258977 - 15	1Bm	/ 100.0 Up dB	000 k per Freg(
9.0000 1	1 11	.000 M	10	3.00 k	-21.27	7 5.	8160		-22.	71	5.834	42 1
11.000		.000 M		3.00 k	-32.13		8140				5.836	
20.000 h 30.000 h		1.000 M		3.00 k 3.00 k	-53.22		8049 7876		-54.		5.845 5.858	

1. All values typical.

Custom modulation

[real-time mode]

Custom digitally modulated signals [real-time mode]^{1, 2}

Modulation	QPSK	π/ 4DQPSK	16QAM	2FSK	GMSK
Filter		Root Nyquist	Ga	aussian	
Filter factor [a or $B_{b}T$]	0.25	0.25	0.25	0.5	0.5
Modulation index	N/A	N/A	N/A	0.5	N/A
Symbol rate [Msym/s]	4	4	4	1	1
	Error vector magnitude ^{3, 4}			Shift error ^{3, 4}	Global phase error ^{3, 4}
		[% rms]		[% rms]	[degrees rms]
fc = 1 GHz	1.1 (0.7)	1.1 (0.7)	1.0 (0.6)	1.3 (0.8)	0.4 (0.2)
fc = 2 GHz	1.2 (0.8)	1.2 (0.8)	1.0 (0.6)	1.4 (0.9)	0.5 (0.3)
fc = 3 GHz	1.6 (1.0)	1.6 (1.0)	1.5 (0.9)	1.8 (1.0)	0.7 (0.4)
fc = 4 GHz	2.5 (1.4)	2.5 (1.3)	3.3 (1.9)	3.3 (2.0)	1.0 (0.6)
fc = 5 GHz	1.5 (1.0)	1.5 (1.0)	1.2 (0.8)	1.8 (1.2)	0.6 (0.3)
fc = 6 GHz	1.8 (1.2)	1.8 (1.2)	1.4 (1.0)	2.0 (1.4)	0.8 (0.4)

Internal modulation using real-time TDMA personalities [Option 402]²

~	NA	DC	PI	DC	PI	HS	TET	RA ⁴	DECT	GSM D	CS, PCS	EDGE
Error vector magnitude ^{6, 4} [% rms]												
Low EVM mode	1.2	(0.7)	1.2	(0.7)	0.9	(0.5)	0.8	(0.5)				1.2 (0.6)
Low ACP mode	(1	.2)	(0	.9)	(0	.6)	(1	.0)				
Global phase error ²												
rms	N.	/Α	N/	A/	N,	/A	N,	/A	N/A	0.6	(0.3)	N/A
pk										1.9	(1.0)	
Deviation accuracy ² [kHz, rms]	N.	/Α	N,	/A	N,	/A	N,	/Α	2.5 (1.1)	N	/A	N/A
Channel spacing [kHz]	3	0	2	5	3	00	2	5	1728	2	00	200
Adjacent channel power ² [ACP]	Cont.	Burst	Cont.	Burst	Cont.	Burst	Cont.	Burst	N/A	Cont.	Burst	N/A
(Low ACP mode, dBc)												
at adjacent channel ⁷	(35)	(–34)	-	-	-	-	(-70)	(63)		(–37)	(37)	
at 1st alternate channel ⁷	(80)	(—79)	(74)	(74)	(81)	(76)	(81)	(—80)		(-71)	(70)	
at 2nd alternate channel ⁷	(84)	(83)	-	-	(82)	(-79)	(82)	(82)		(84)	(81)	
at 3rd alternate channel ⁷	(85)	(84)	(82)	(82)	-	-	(83)	(83)		(85)	(81)	
Support burst types	Cus	tom	Cus	tom	Cus	tom	Cus	tom	Custom	Custom	, normal	
	up/dov	vn TCH	up/dov	vn TCH	TCH,	sync	up contr	ol 1 & 2,	dummy B 1 & 2,	Fcorr,	sync,	
			up	Vox			up no	rmal,	traffic B,	dummy	, access	
							down r	normal,	low capacity			
Scramble capability					Y	es	Ye	es				

1. This level of performance can be attained using the external I/Q inputs, provided the quality of the baseband signal meets or exceeds that of the ESG baseband generator.

2. Parentheses denote typical performance.

- 3. Specifications apply at power levels ≤ +4 dBm [≤ +5 dBm for Option 506, and ≤ +8 dBm for Option UNB] with default scale factor of I/Q outputs.
- 4. Valid after executing I/Q calibration and maintained within +/- 5 °C of the calibration temperature.

7. The "channel spacing" determines the offset size of the adjacent and alternate channels: Adjacent channel offset = 1 x channel spacing, 1st alternate channel = 2 x channel spacing, 2nd alternate channel = 3 x channel spacing, etc.

^{5.} ACP for TETRA is measured over a 25 kHz bandwidth, with an 18 kHz root raised cosine filter. Low ACP mode is valid at power levels < -1 dBm [< 1 dBm for Option 506 and < +4 dBm for Option UNB].

Specifications apply for the symbol rates, filter, filter factors [a or BbT] and default scaling factor specified for each standard, and at power levels ≤ +7 dBm [≤ +10 dBm for Option UNB].

GSM/GPRS [real-time mode] [Option 402]

Coding scheme	Full-rate speech [TCH/FS] CS-1, CS-4
Data	PN9 or PN15 The selected data sequence is coded continuously across the RLC data block as per ETSI TS 100 909, 30 TS 05.03, V8.9.0, 2000-11 [release 1999] An independent version of the selected data sequence is coded across the MAC header.
Frame structure	26-frame multi-frame structure as per ETSI GSM, 05.01 version 6.1.1 [1998-07]. [Coding is done on frames 0-11, 13-24, of the multi-frame Frame 25 is idle [RF blanked].]
Adjacent timeslots	
Data	PN9, PN15 coded as per ETSI TS 100 909, 3GPP TS 05.03, V8.9.0, 2000-11 [release 1999].
Frame structure	26-frame multi-frame structure as per ETSI GSM, 5.01 version 6.1.1 [1998-07].
ultiframe measurements ¹	
GSM measurement modes	
Static sensitivity	RBER at user-specified power level measured. [This is the complete conformance test as defined in pri-ETS 300 609-1 [GSM 11.21] version 4.12.0 [Dec 98 section 7.3.4.]
Sensitivity search	Automatically finds the input level [sensitivity] that cau a user-specified RBER [normally 2%] for class II bits.
Maximum frame coun	t 6,000,000 speech frames
GSM measurement results	Class Ib bit-error ratio [RBER for TCH/FS] Class II bit-error ratio [RBER for TCH/FS] Frame erasure ratio [FER] Downlink error frame count Class Ib bit-error count Class II bit-error count Erased frame count Total frame count
Maximum RBER	50%

Alternate time slot power level control

[Valid for standard attenuator only. Not applicable to Option UNB or Option 506] Amplitude is settled within 0.5 dB in 20 µsecs, +4 to -136 dBm at 23 ±5 °C

Coding scheme	MCS-1: uplink and downlink, MCS-5: uplink and downlin MCS-9: uplink and downlink, E-TCH/F43.2
Data	PN9 or PN15 The selected data sequence is fully coded continuously across the RLC data blocks according to MCS-1, MCS-5, MCS-9 or E-TCH/F43.2. An independent version of the selected data sequence is coded across th unused RLC/MAC header fields [The CPS header field i as defined in GSM 04.60 V8.50].
Frame structure	52-frame multi-frame structure for EDGE/EGPRS channel as per ETSI TS 100 909, 3GPP TS 05.03, V8.9.0, 2000-11 [release 1999]. [Coding is done on frames 0-11, 13-24, 26-37, 39-50 on a 52 PDCH multi-frame. Frame 25 and 51 are idle [RF blanked].]
Adjacent timeslots	
Data Frame structure	Coded MCS-1, MCS-5 or MCS-9 with continuous PN9 o PN15 sequence data payload. Uncoded PN9, PN15. Note: Maximum of 4 timeslots can be turned on with EDGE/EGPRS multi-frame coded data. EDGE/EGPRS PDCH multi-frame. Repeating EDGE frame.
ultiframe measurements ¹	
EDGE measurement modes Static sensitivity	BER/BLER at user-specified power level measured; based on bit errors in total unencoded data, and block errors in coded channels.
Sensitivity search BER/BLER	Automatically finds the input level [sensitivity] that cause user-specified BER [uncoded] or BER [coded].
EDGE measurement results	Erased data block count/rate for coded channel [MCS-1, MCS-5 or MCS-9]. Total data block count for coded channel [MCS-1, MCS-5 or MCS-9]. Payload bit error count/rate for raw BER. Total burst count for raw BER. Data block count which contains residual bit errors and bit error count. Downlink error reporting

EDGE/EGPRS

[real-time mode] [Option 402]

^{1.} Measurements also require Option 300.

GSM/EDGE base station bit error rate test [BERT] [Option 300]

This is a system of two instruments; an ESG with Option 300, and a VSA with Option 300. Both are required. Option 300 for the ESG requires Option 601 or 602, the TDMA personalities [Option 402], and the UN7 BER board. The VSA functions as an IF downconverter. It may be used simultaneously to make transmitter measurements on the loop back signal.

GSM BTS test only

E4406A VSA series transmitter tester with Options BAH [GSM measurement personality] and Option 300 [321.4 MHz output].

GSM/EDGE BTS test

E4406A VSA series transmitter tester with Option 202 [GSM and EDGE measurement personality] and Option 300 [321.4 MHz output].

Test technique	RF loopback
Supported systems GSM 400	
GSM 850 GSM 900 [P-GSM] DCS 1800	
PCS 1900 E-GSM [extended]	
Minimum power level	–136 dBm [ESG minimum]
Maximum power level	+13 dBm [option dependent]
Power level accuracy	$\pm 0.5 \text{ dB} [23^{\circ} \pm 5 \text{ °C}]$ [power and frequency dependent]
Relative power level	0 to ±130 dB relative to timeslot under test. [Limited only by output power range of the ESG.]
Timeslot under test Timeslots tested	0 to 7 A single timeslot is tested at one time.
Francian	[No frequency hopping.] None
Encryption	
Measurement triggers	Immediate, trigger key, external, remote [LAN, GPIB, RS-232]
Measurement indication	Pass/fail
BCH sync	BCH signal from the BTS is used to determine TCH frame and multi-frame location.
TCH sync	The idle frame [no RF] in the TCH signal itself is used to determine the TCH multi-frame location and so generate the multi-frame sync signal.
Threshold	Termination of measurement when error count exceeds user-specified threshold.

Bit error rate [BER] analyzer [Option UN7]

Clock rate	100 Hz to 60 MHz		
Supported data patterns	PN9, 11, 15, 20, 23		
Resolution	10 digits		
Bit sequence length 100 bits to 4.294 Gbits after synchronizatio			
Features			
	Input clock phase adjustment and gate delay		
	Adjustable input threshold		
	Hi/lo threshold selectable from 0.7 V [TTL], 1.4 V [TTL]		
	1.65 V [CMOS 3.3], 2.5 V [CMOS 5.0]		
	Direct measurement triggering		
	Data and reference signal outputs		
	Real-time display		
	Bit count		
	Error-bit-count		
	Bit error rate		
	Pass/fail indication		
	Valid data and clock detection		
	Automatic re-synchronization		
	Special pattern ignore		

General Characteristics

Operating characteristics

Power requirements	00 to 254 V/: 50	or 60 Hz; 200 \// mox	vimum	
rower requirements	90 to 254 V; 50, or 60 Hz; 300 W maximum, power factor corrected. Not for 400 Hz use. ¹			
Operating temperature range ²	0 to 55 °C			
Storage temperature range	–40 to 71 °C			
Shock and vibration	Meets MIL-STD	-28800E Type III, Cla	ss 3.	
Leakage	Conducted and radiated interference meets MIL-STD-461C CE02 Part 2 and CISPR 11. Leakage is typically < 1 μ V [nominally 0.1 μ V with a 2-turn loop] at \leq 1000 MHz, measured with a resonant dipole antenna, one inch from any surface with output level < 0 dBm [all inputs/outputs properly terminated].			
Storage registers	Memory is shared by instrument states, user data files, non-volatile waveforms, sweep list files and waveform sequences. There is 14 MB of flash memory standard in the ESG. With Option 005, there is 6 GB of storage. Depending on available memory, a maximum of 1000 instrument states can be saved.			
Weight		net, < 23 kg [50 lb.] s	shipping	
Dimensions		6 mm W x 432 mm D 8 in W x 17 in D]		
Remote programming Interface	GPIB [IEEE-488.2-1987] with listen and talk, RS-232, LAN [10BaseT].			
Control languages ³	SCPI version 1996.0, also compatible with 8656B and 8657A/B/C/D/J1 mnemonics.			
Functions controlled	All front panel functions except power switch and			
ISO compliant	The E4438C ESG is manufactured in an ISO-9001 registered facility in concurrence with Agilent Technologies commitment to quality.			
Reverse power protection				
250 kHz to 2 GHz 4 > 2 to 4 GHz 4 > 4 to 6 GHz N	<u>Standard</u> 7 dBm 4 dBm V/A 50 V	With Option 30 dBm 30 dBm 30 dBm	506	
SWR ⁴				
	Standard	Option UNB	Option 506	
250 kHz to 2.2 GHz > 2.2 GHz to 3 GHz > 3 GHz to 4 GHz > 4 GHz to 6 GHz	(< 1.5:1) (< 1.4:1) (< 1.5:1) N/A	(< 1.5:1) (< 1.5:1) (< 1.7:1) N/A	(< 1.6:1) (< 1.4:1) (< 1.7:1) (< 1.8:1)	
Output impedance	50 Ω nominal			

^{1.} For 400 Hz systems, order transformer 70001-60066.

Save and recall of user files and instrument states from non-volatile storage is guaranteed only over the range 0 to 40 °C.
 ESG series does not implement 8657A/B "Standby" or "On" [R0 or R1, respectively] mnemonics.

^{4.} Parentheses denote typical performance.

General Characteristics

Accessories

Accessories	Transit case	Part number 9211-1296
Inputs and outputs		
All front panel connectors can be moved to rear with Option 1EM.	10 MHz input	Accepts a 1, 2, 5, or 10 MHz ±10 ppm [standard timebase] or ±1 ppm [high-stability timebase] reference signal for operation with an external timebase. Nominal input level –3.5 to +20 dBm, impedance 50 ohms. [BNC, rear panel]
	10 MHz output	Outputs the 10 MHz reference signal. Level nominally +3.9 dBm ±2 dB. Nominal output impedance 50 ohms. [BNC, rear panel]
	Alternate power input	Accepts CMOS ¹ signal for synchronization of external data and alternate power signal timing. The damage levels are –0.5 to +5.5 V. [Auxiliary I/O connector, rear panel]
	Baseband generator reference input	Accepts 0 to +20 dBm sinewave, or TTL squarewave, to use as reference clock for the baseband generator. Phase locks the internal data generator to the external reference; the RF frequency is still locked to the 10 MHz reference. Rate is 250 kHz to 100 MHz, 50 ohms nominal, AC coupled. [BNC, rear panel]
	Burst gate input	The burst gate in connector accepts a CMOS ¹ signal for gating burst power in digital modulation applications. The burst gating is used when you are externally supplying data and clock information. The input signal must be synchronized with the external data input that will be output during the burst. The burst power envelope and modulated data are internally delayed and re-synchronized. The input signal must be CMOS high for normal burst RF power or CW RF output power and CMOS low for RF off. The damage levels are –0.5 to +5.5 V.
		This female BNC connector is provided on signal generators with Option 601 or 602. On signal generators with Option 1EM, this input is relocated to a rear panel SMB connector. With Option 401, this connector is used for the even second synchronization input.
	Coherent carrier output ²	Outputs RF modulated with FM or Φ M, but not IQ, pulse or AM. Nominal power –2 dBm ±5 dB. Nominal impedance 50 ohms. Frequency range from > 250 MHz to 4 GHz. For RF carriers below this range, output frequency = 1 GHz – frequency of RF output. Damage levels 20 VDC and 13 dBm reverse RF power.

1. Rear panel inputs and outputs are 3.3 V CMOS, unless indicated otherwise. CMOS inputs will accept 5 V CMOS, 3 V CMOS, or TTL voltage levels.

2. Coherent carrier is modulated by FM or Φ M when enabled.

Data clock input	[SMA, rear panel] The CMOS ¹ compatible data clock connector accepts an externally supplied data-clock input for digital modulation applications. The expected input is a bit clock signal where the falling edge is used to clock the data and symbol sync signals.
	The maximum clock rate is 50 MHz. The damage levels are -0.5 to $+5.5$ V.
	This female BNC connector is provided on signal generators with Option 601 or 602. On signal generators with Option 1EM, this input is relocated to a rear panel SMB connector.
Data clock output	Relays a CMOS ¹ bit clock signal for synchronizing serial data. [Auxiliary I/O connector, rear panel]
Data input	The CMOS ¹ compatible data connector accepts an externally supplied data input for digital modulation applications. CMOS high is equivalent to a data 1 and a CMOS low is equivalent to a data 0.
	The maximum data rate is 50 Mb/s. The data must be valid on the data clock falling edges [normal mode] or the symbol sync falling edges [symbol mode]. The damage levels are -0.5 to +5.5 V.
	This female BNC connector is provided on signal generators with Option 601 or 602. On signal generators with Option 1EM, this input is relocated to a rear panel SMB connector.
Data output	Outputs serial data from the internal data generator or the externally supplied signal at the data input. CMOS ¹ signal. [Auxiliary I/O connector, rear panel]
Event 1 output	In real-time mode, outputs pattern or frame synchronization pulse for triggering or gating external equipment. May be set to start at the beginning of a pattern, frame, or timeslot and is adjustable to within ± one timeslot with one bit resolution.
	In arbitrary waveform mode, this connector outputs the timing signal generated by marker 1. [BNC, rear panel]
Event 2 output	In real-time mode, outputs data enable signal for gating external equipment. Applicable when external data is clocked into internally generated timeslots. Data is enabled when signal is low.
	In arbitrary waveform mode, this connector outputs the timing signal generated by marker 2. [BNC, rear panel]
Event 3 output	In arbitrary waveform mode, this connector outputs the timing signal generated by marker 3. [Auxiliary I/O connector, rear panel]
Event 4 output	In arbitrary waveform mode, this connector outputs the timing signal generated by marker 4. [Auxiliary I/O

1. Rear panel inputs and outputs are 3.3 V CMOS, unless indicated otherwise. CMOS inputs will accept 5 V CMOS, 3 V CMOS, or TTL voltage levels.

External 1 input	connector, rear panel] This BNC input connector accepts a $\pm 1 V_{peak}$ signal for AM, FM, pulse, burst, and phase modulation. For all these modulations, $\pm 1 V_{peak}$ produces the indicated deviation or depth. When ac-coupled inputs are selected for AM, FM, or phase modulation and the peak input voltage differs from 1 V_{peak} by more than 3%, the hi/lo annunciator light on the display. The input impedance is 50 ohms and the damage levels are 5 V_{rms} and 10 V_{peak} .
	If you configure your signal generator with Option 1EM, this input is relocated to a female BNC connector on the rear panel.
External 2 input	This BNC input connector accepts a ±1 V _{peak} signal for AM, FM, phase modulation, and pulse modulation. With AM, FM, or phase modulation, ±1 V _{peak} produces the indicated deviation or depth. With pulse modulation, +1 V is on and 0 V is off. When ac-coupled inputs are selected for AM, FM, or phase modulation, and the peak voltage differs from 1 V _{peak} by more than 3%, the hi/lo annunciator light on the display. The input impedance is 50 ohms and the damage levels are 5 V _{rms} and 10 V _{peak} .
	If you configure your signal generator with Option 1EM, this input is relocated to a female BNC connector on the rear panel.
GPIB	Allows communication with compatible devices. [rear panel]
l input	Accepts an I input either for I/Q modulation or for wideband AM. Nominal input impedance 50 or 600 ohms. Damage levels are 1 V _{rms} and 10 V _{peak} . [BNC, front panel]
I out and Ω out ¹	The I out and Q out connectors output the analog components of I/Q modulation from the internal baseband generator. The nominal output impedance of these connectors are 50 Ω , DC-coupled. The damage levels are > +3.5 V and < -3.5 V. The output signal levels into a 50 Ω load are as follows: • (0.5 V _{peak} ,), corresponds to one unit length of the I/Q vector. • (0.7 V _{peak}), for peaks for $\pi/4$ DQPSK. • (1.6 V _{p-p}) maximum [Options 601, 602, 001, 002 only].
	These female BNC connectors are provided on signal generators with Option 601 or 602. On signal generators with Option 1EM, these inputs are relocated to rear panel SMB connectors.

^{1.} Parentheses denote typical performance.

\overline{I} and $\overline{\Omega}$ out	\overline{I} and $\overline{\Omega}$ are used in conjunction with I and Ω to provide a balanced baseband stimulus. Balanced signals are signals present in two separate conductors that are
	symmetrical about the common mode offset, and are opposite in polarity [180 degrees out of phase].
	These female BNC connectors are provided only on signal generators with Option 601 or 602. If you configure your signal generator with Option 1EM, these inputs are relocated to rear panel SMB connectors.
LF output	Outputs the internally-generated LF source. Outputs 0 to 2.5 V _{peak} into 50 ohms, or 0 to 5 V _{peak} into high impedance. [BNC, front panel]
Pattern trigger inpu	t Accepts CMOS ¹ signal to trigger internal pattern or frame generator to start single pattern output. Minimum pulse width 100 ns. The damage levels are –0.5 to +5.5 V. [BNC, rear panel]
Q input	Accepts a Q input for I/Q modulation. Nominal input impedance 50 or 600 ohms, damage levels are 1 V _{rms} and 10 V _{peak} . [BNC, front panel]
RF output	Nominal output impedance 50 ohms. [type-N female, front panel]
Sweep output	Generates output voltage, 0 to +10 V when signal generator is sweeping. Output impedance < 1 ohm, can drive 2000 ohms. [BNC, rear panel]
Symbol sync input	The CMOS ¹ compatible symbol sync connector accepts an externally supplied symbol sync for digital modulation applications. The expected input is a symbol clock signal. It may be used in two modes. When used as a symbol sync in conjunction with a data clock, the signal must be high during the first data bit of the symbol. The signal must be valid during the falling edge of the data clock signal and may be a single pulse or continuous. When the symbol sync itself is used as the [symbol] clock, the falling edge is used to clock the data signal.
	The maximum clock rate is 50 MHz. The damage levels are –0.5 to +5.5 V. [BNC, front panel]
	This female BNC connector is provided on signal generators with Option 601 or 602. On signal generators with Option 1EM, this input is relocated to a rear panel SMB connector.
Symbol sync output	t Outputs CMOS ¹ symbol clock for symbol synchronization, one data clock period wide. [Auxiliary I/O connector, rear panel]
Trigger input	Accepts CMOS ¹ signal for triggering point-to-point in manual sweep mode, or to trigger start of LF sweep. the damage levels are –0.5 to +5.5 V. [BNC, rear panel]
Trigger output	Outputs a TTL signal: high at start of dwell, or when waiting for point trigger in manual sweep mode; low when dwell is over or point trigger is received, high or low 2 µs pulse at start of LF sweep. [BNC, rear panel]

1. Rear panel inputs and outputs are 3.3 V CMOS, unless indicated otherwise. CMOS inputs will accept 5 V CMOS, 3 V CMOS, or TTL voltage levels.

General Characteristics

Accepts CMOS ¹ or 75 Ω input. Polarity is selected.
Clock duty and inputs cycle is 30% to 70%. [SMB, rear panel]
Outputs a CMOS ¹ signal that is low when sync is lost. Valid only when measure end signal is high. [Auxiliary I/O connector, rear panel]
Outputs a CMOS ¹ signal that is low when no data is detected. Valid only when measure end is high. [Auxiliary I/O connector, rear panel]
Outputs CMOS ¹ signal when error bit is detected. Pulse width matches the input clock. [Auxiliary I/O connector, rear panel]
Outputs a CMOS ¹ signal that is high for fail and low for pass. Valid only on measure end signal falling edge. [Auxiliary I/O connector, rear panel]
Outputs a CMOS ¹ signal that is high during measurement. Trigger events are ignored while high. [Auxiliary I/O connector, rear panel]
Accepts CMOS ¹ signal to initiate BER measurement. Polarity is selectable; available when trigger source is selected as "AUX I/O". Damage levels are The damage levels are –0.5 to +5.5 V. [Auxiliary I/O connector, rear panel]
Accepts a 321.4 MHz IF signal for GSM/EDGE/loopback testing. Input amplitude range -7 dBm to -22 dBm. Nominal input impedance 50 ohms. [SMB, rear panel]

LAN connector

LAN communication is supported by the signal generator via the LAN connector. It is functionally equivalent to the GPIB connector. The LAN connector enables the signal generator to be remotely programmed by a LAN-connected computer. The distance between a computer and the signal generator is limited to 100 meters [10BaseT]. For more information about the LAN, refer to the *Getting Started* chapter in the *Programming Guide*.

Data transfer speeds ²		
LAN [FTP]	file transfer to volatile memory	(700 KB/sec)
	to hard drive	(500 KB/sec)
LAN [SCPI]	command transfer to volatile memory	(146 KB/sec)
	to hard drive	(128 KB/sec)
Internal file transf	er from hard drive to volatile memory	(1280 KB/sec)

Agilent's IO Libraries Suite ships with the E4438C to help you quickly establish an errorfree connection between your PC and instruments – regardless of the vendor. It provides robust instrument control and works with the software development environment you choose.

2. Parentheses denote typical performance.

^{1.} Rear panel inputs and outputs are 3.3 V CMOS, unless indicated otherwise. CMOS inputs will accept 5 V CMOS, 3 V CMOS, or TTL voltage levels.

RS-232 connector

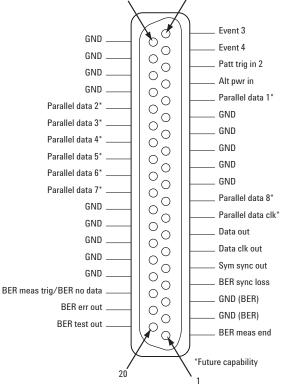
This male DB-9 connector is an RS-232 serial port that can be used for controlling the signal generator remotely. It is functionally equivalent to the GPIB connector. The following table shows the description of the pinouts. The pin configuration is shown below.

Pin number	Signal description	Signal name
1	No connection	
2	Receive data	RECV
3	Transmit data	XMIT
4	+5 V	
5	Ground, 0 V	
6	No connection	
7	Request to send	RTS
8	Clear to send	CTS
9	No connection	
5 4	3 ² ¹	

View looking into rear panel connector

Auxiliary I/O connector

This connector enables you to access the inputs and outputs of the baseband generator. The figure below shows the Auxiliary I/O ping connector copflg uration.



View looking into rear panel connector

Mating connector

37 pin male D-subminiature, available from AMP, 3M, others.

Ordering Information¹

Frequency options	
i requency options	501 1 GHz frequency range
	502 2 GHz frequency range
	• 503 3 GHz frequency range
	504 4 GHz frequency range
	• 506 6 GHz frequency range [requires option UNJ, includes mechanical attenuator]
Performance enhancement options	UNB High output power with mechanical attenuator
	[included with 506]
	UNJ Enhanced phase noise performance [includes 1E5]
	1E5 High-stability time base
	1EM Moves all front panel connectors to rear
	003 ² ESG digital output connectivity with N5102A Baseband Studio digital
	interface module
	 004² ESG digital input connectivity with N5102A Baseband Studio digital interface module
	601 Internal baseband generator with 8 MSa and digital bus capability
	[40 MB] of memory
	 602 Internal baseband generator with 64 MSa and digital bus capability [320 MB] of memory
	005 ³ 6 GB internal hard drive
	UN7 Internal bit-error-rate analyzer
	300 GSM/EDGE base station loopback BERT
Simulanation additions	
Signal creation software ³	3GPP W-CDMA FDD personality
	cdma2000 and IS-95-A personality
	TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA)
	Calibrated noise (AWGN) personality CDS accessed by
	 GPS personality Signal Studio for 1xEV-DO
	Signal Studio for 1xEV-DO signal Studio for 1xEV-DV and cdma2000
	Signal Studio for 802.11 WLAN
	 Signal Studio for Bluetooth™
	Signal Studio for enhanced multitone
	Signal Studio for HSDPA over W-CDMA
	 Signal Studio for TD-SCDMA (TSM)
	 Signal Studio for noise power ratio (NPR)
	 Signal Studio for S-DMB
	Signal Studio for pulse building
	Signal Studio for jitter injection
	Signal Studio toolkit
	Signal Studio for 802.16-2004 (WiMAX)
Baseband Studio products ⁴	
-	N5102A Baseband Studio digital signal interface module
	N5110A Baseband Studio for waveform streaming ⁵ N5115A Baseband Studio for fodiar ⁵
	 N5115A Baseband Studio for fading⁵ N5101A Baseband Studio PCI card⁵
System accessories	1CP Rack mount kit with handles
	1CN Front handle kit

1. All options should be ordered using E4438C-xxx, where the xxx represents the option number. For more information, please refer to the configuration guide publication number 5988-4085EN.

2. Requires either Option 601 or 602 (baseband generator) to function.

3. Requuires Option 001, 002, 601, or 602.

4. Agilent's Baseband Studio is a suite of baseband signal applications and accessories that initially work with the E4438C ESG and E8267C PSG vector signal generators to enhance Agilent's signal creation and signal generation tool set. For details visit www.agilent.com/find/basebandstudio.

5. Baseband Studio for waveform streaming and for fading both require a PC equipped with the Agilent N5101A Baseband Studio PCI card. The PCI card is not functional as a stand-alone product.

Related Literature

Application literature	 <i>RF Source Basics</i>, a self-paced tutorial (CD-ROM), literature number 5980-2060E. <i>Digital Modulation in Communications Systems—An Introduction</i>, Application Note 1298, literature number 5965-7160E. <i>Using Vector Modulation Analysis in the Integration, Troubleshooting</i> <i>and Design of Digital Communications Systems</i>, Product Note, literature number 5091-8687E. <i>Testing CDMA Base Station Amplifiers</i>, Application Note 1307, literature number 5967-5486E. <i>Understanding GSM/EDGE Transmitter and Receiver Measurements for</i> <i>Base Transceiver Stations and Their Components</i>, Application Note 1312, literature number 5968-2320E. <i>Understanding CDMA Measurements for Base Stations and their</i> <i>Components</i>, Application Note 1311, literature number 5968-0953E. <i>Testing and Troubleshooting Digital RF Communications Receiver</i> <i>Designs</i>, Application Note 1314, literature number 5968-3579E. <i>Signal Generators - Vector</i>, <i>Analog</i>, and <i>CW Models</i>, Selection Guide, literature number 5965-3094E.
Product literature	 <i>E4438C ESG Vector Signal Generator</i>, Brochure, literature number 5988-3935EN. <i>E4438C ESG Vector Signal Generator</i>, Configuration Guide, literature number 5988-4085EN. <i>IntuiLink Software</i>, Data Sheet, literature number 5980-3115EN.
	 E4438C ESG signal generation firmware personalities 3GPP W-CDMA (FDD) Personalities - Option 400, Technical Overview, literature number 5988-4449EN cdma2000 and IS-95A Personalities - Option 401, Technical Overview, literature number 5988-4430EN GPS Personality - Option 409, Technical Overview, literature number 5988-6256EN TDMA Personalities (GSM/EDGE/NADC/PDC/PHS/TETRA/DECT) - Option 402, Technical Overview, literature number 5988-4431EN
	 E4438C ESG Signal Studio software personalities Signal Studio for 1xEV-DO - Option 404, Technical Overview, literature number 5988-5459EN Signal Studio for 1xEV-DV and cdma2000 - Option 414, Technical Overview, literature number 5988-9123EN Signal Studio for 802.11 WLAN - Option 417, Technical Overview, literature number 5988-8618EN Signal Studio for Bluetooth - Option 406, Technical Overview, literature number 5988-5458EN Signal Studio for Enhanced Multitone - Option 408, Technical Overview, literature number 5988-5639EN Signal Studio for Noise Power Ratio - Option 421, Technical Overview, literature number 5988-6552EN

• Signal Studio for TD-SCDMA (TSM) - Option 411, Technical Overview, literature number 5988-6552EN

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Agilent Technologies' Test and Measurement Support, Services, and Assistance

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Our Promise

Our Promise means your Agilent test and measurement equipment will meet its advertised performance and functionality. When you are choosing new equipment, we will help you with product information, including realistic performance specifications and practical recommendations from experienced test engineers. When you receive your new Agilent equipment, we can help verify that it works properly and help with initial product operation.

Your Advantage

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